NSN 5961-01-580-2331

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-580-2331 **Overall Length:** 5.5 millimeters **Overall Height:** 2.3 millimeters **Overall Width:** 2.8 millimeters **End Application:** Combined system interim acc-rpc-sfp Voltage Rating In Volts Per Characteristic: 12.4 breakdown voltage, dc and 1.2 forward voltage, dc **Current Rating Per Characteristic:** 50.00 amperes peak forward surge current **Special Features:** Junction temperature: 150 degrees c; storage temp. Range: m65/p150 degrees c; junction capacitance: 850 pf; glass passivated junction; stand-off voltage range: 8.2 v to 200.0 v; lead-free component; aprrox. Weight: 77 mg

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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